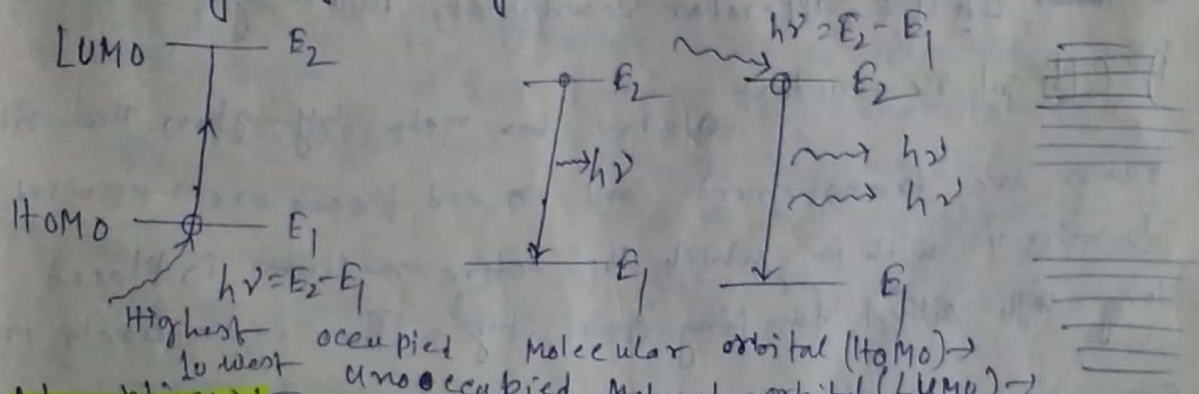


① Laser - Laser is a device by which we can produce wave or light with following properties.

- (i) All the wave coming from laser are coherent
- (ii) Wave is monochromatic
- (iii) Laser beam is ~~un~~ unidirectional

LASER - Light Amplification by Stimulated Emission of Radiation

Metastable state - At the life time of an excited states of atom is very large nearly $\approx 10^{-3}$ sec is called Metastable states



Absorption - At the atom is initially in the lowest state E_1 , it can be raised to E_2 by absorption of a photon of energy $h\nu = E_2 - E_1$, this is called absorption.

Spontaneous emission - At the atom initially in the upper state E_2 , it can drop to lowest state E_1 by emitting of a photon of energy $h\nu$. This process is called spontaneous emission.

Excited system - When the electron is in upper level the system is called excited system.

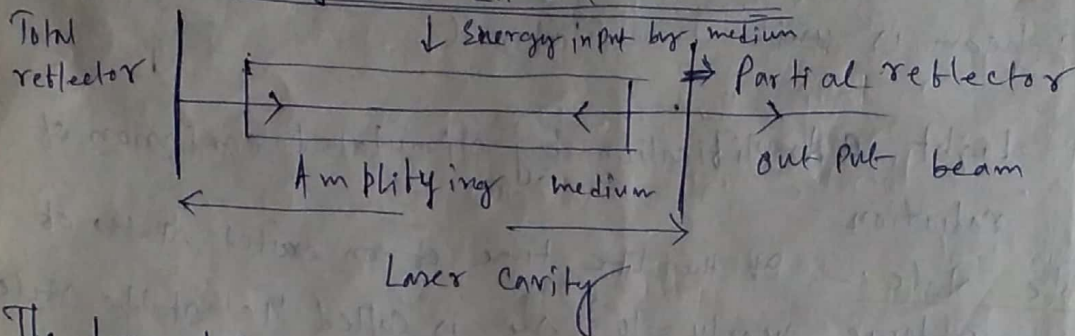
Population inversion - When in an electronic system the lower level are empty or less populated, then the upper level, the system is called population inversion system.

Stimulated emission - At the atom initially in the upper level E_2 , again excited by another photon of energy $h\nu = E_2 - E_1$, then, two will be emitted.

(2)

This process is called stimulated emission. out of two photons one is due to spontaneous emission and another is from excitation of excited electron.

Schematic diagram of LASER apparatus:-



The ~~laser~~ LASER apparatus consist of following component

i) Optical resonator:-

It is a box made by glass. The side faces are transparent and end faces are mirrored to mirror with in which the active medium is placed along with optical pumping facility. There is a hole in one end face of resonator, through which the LASER light comes out.

ii) Active medium:-

The active medium is mostly gas in LASER sometime it is liquid, solid or some other medium, with in the active medium mean LASER action will held.

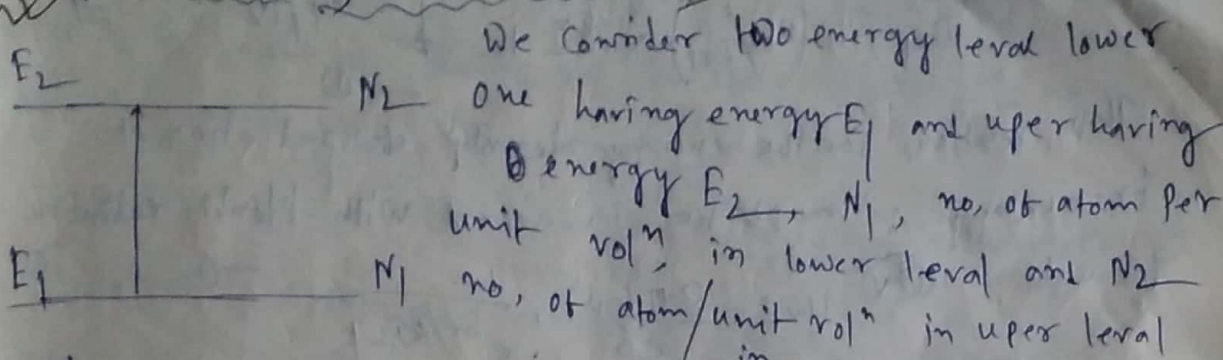
iii) Optical pumping:-

The process in which the atom or molecule of active medium are excited. Generally it is electric spark, thermal or chemical reaction.

iv) Mirror:-

The end faces of resonator are mirror or reflectors. It make the LASER light unidirectional.

Stimulated A B coefficient (3)



We consider two energy level lower one having energy E_1 and upper having energy E_2 , N_1 no. of atom per unit volⁿ in lower level and N_2 no. of atom/unit volⁿ in upper level at one instant. Let the system is in thermal equilibrium at tempⁿ T and energy of frequency ν having energy density U_ν .

i) Absorption: - The Probable rate of transition by absorption from level 1 to 2 is proportional to U_ν

1. $P_{12} = B_{12} U_\nu$ [B_{12} = Stimulated coefficient of absorption of radiation]

The no. of atom in state one that absorb a photon and rise to state two per unit time is given by $N_1 P_{12} = N_1 B_{12} U_\nu$

(ii) Spontaneous emission:

No. of atom in state two that drop to state one by spontaneous per unit time is $N_2 A_{21}$.

[A_{21} = Stimulated const. for spontaneous emission]

(iii) Stimulated emission:

No. of atom in state two. The Probability of stimulated emission from state 2 to state 1 is proportional to energy density U_ν .

\therefore No. of atom under going stimulated emission from level 2 to level 1 per unit time is $N_2 B_{21} U_\nu$.

in equilibrium the absorption and emission per unit time is equal $N_1 B_{12} U_\nu = N_2 A_{21} + N_2 B_{21} U_\nu$

$$N_2 A_{21} = N_2 B_{21} U_\nu - N_1 B_{12} U_\nu$$

$$= U_\nu (N_2 B_{21} - N_1 B_{12})$$

$$\therefore U_\nu = \frac{N_2 A_{21}}{(N_2 B_{21} - N_1 B_{12})} = \frac{A_{21}}{B_{21}} \cdot \frac{1}{\frac{N_1}{N_2} \left(\frac{B_{12}}{B_{21}} \right) - 1}$$

$$= \frac{A_{21}}{B_{21}} \cdot \frac{1}{(B_{12}/B_{21}) e^{h\nu/kT} - 1} \quad \left[\because N_1/N_2 = e^{h\nu/kT} \right] \quad \text{--- (1)}$$

This relation for the energy density of radiation of frequency ν must be in accord with Planck's radiation formula,

$$u_\nu = \frac{8\pi h\nu^3}{c^3} \cdot \frac{1}{e^{h\nu/kT} - 1} \quad \text{--- (2)}$$

Comparing (1) & (2) we get

$$B_{12} = B_{21} \text{ and } A_{21}/B_{21} = 8\pi h\nu^3/c^3$$

(i) $B_{12} = B_{21}$ \therefore probability of absorption and stimulating emission are equal.

(ii) $A_{21}/B_{21} = 8\pi h\nu^3/c^3$ probability of spontaneous emission increases very rapidly with energy (ν^3)

Threshold condition for LASER action:

The radiation within the active medium of optical resonator suffers multiple reflection from the reflectors placed at the two ends of resonator.

The radiation of active medium suffers losses due to absorption, transmission, scattering of active medium by reflector and diffraction.

For sustained laser action the losses are

compensated by induced transitions in the active medium. To sustain the laser action a minimum population inversion density is required, this is called

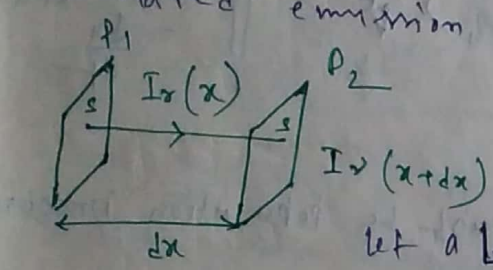
threshold population inversion.

If t_p is the life of a photon in active medium then $1/t_p$ is the rate of loss of energy.

Let within the active medium there is assembly of atoms with N_1 atom per unit volⁿ in stat E_1 and N_2 no of atom per unit volⁿ in stat E_2 .

The transition probability for absorption is

$B_{12} U_\nu N_1$, spontaneous emission $N_2 A_{21}$ and for stimulated emission $B_{21} U_\nu N_2$



Let a laser beam of energy density U_ν propagate through a active medium along x -direction

and consider a thickness dx and cross sectional area S .

Energy loss/sec due to absorption in volum $S dx$

$$= B_{12} U_\nu N_1 (S dx) h \nu$$

Energy gain per sec due to stimulated emission in volⁿ $S dx = B_{21} U_\nu N_2 (S dx) h \nu$

∴ Rate of increase of energy in volⁿ $S dx$

$$= B_{21} U_\nu N_2 (S dx) h \nu - B_{12} U_\nu N_1 (S dx) h \nu$$

$$= (N_2 - N_1) B U_\nu h \nu (S dx) \quad \left| \begin{array}{l} B_{12} = B_{21} = B \end{array} \right.$$

Net energy leaving the volum $S dx$ per sec

$$= [I_\nu(x+dx) - I_\nu(x)] S$$

$$= (dI_\nu) S = \frac{dI_\nu}{dx} dx S$$

∴ For sustained laser action

$$\Rightarrow (N_2 - N_1) B U_\nu h \nu (S dx) = \frac{dI_\nu}{dx} dx S$$

$$\Rightarrow \frac{dI\nu}{dx} = (N_2 - N_1) B u\nu h\nu$$

∴ The rate of increase of intensity is

$$\begin{aligned} \left(\frac{dI\nu}{dt}\right)_{\text{gain}} &= \frac{dI\nu}{dx} \cdot \frac{dx}{dt} \\ &= \frac{dI\nu}{dx} \cdot \nu \\ &= (N_2 - N_1) B u\nu h\nu \cdot \nu \end{aligned}$$

ν = velocity of light in the medium = $\frac{dx}{dt}$

∴ for $\left(\frac{dI\nu}{dt}\right)_{\text{gain}} > 0$ when $N_2 > N_1$

∴ For Laser action there must be population inversion

The rate of loss of intensity is

$$\left(\frac{dI\nu}{dt}\right)_{\text{loss}} = \frac{I\nu}{t_p}$$

∴ for the condition sustained laser action is -

$$\left(\frac{dI\nu}{dt}\right)_{\text{gain}} \geq \left(\frac{dI\nu}{dt}\right)_{\text{loss}}$$

$$\Rightarrow (N_2 - N_1) B u\nu h\nu \nu \geq \frac{I\nu}{t_p}$$

$$\text{Now } A/B = \frac{8\pi h \nu^3}{c^3}$$

$\frac{1}{A_{21}}$ = $t_{s,p}$ = spontaneous life of upper state.

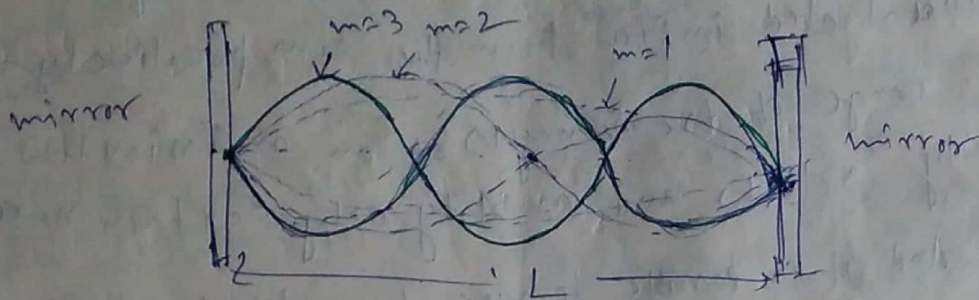
A_{21} is spontaneous emission transition probability.

$$I\nu = u\nu$$

$$\therefore (N_2 - N_1) \geq \frac{8\pi t_{s,p} \nu^2}{c^3 t_p}$$

Standing waves:

The reflection field inside the resonator gives rise to a stationary wave pattern with a node at each mirror



When the cavity resonates, the distance L betⁿ the mirrors has clearly an integral multiple of half wave lengths.

$$\therefore L = \frac{m\lambda}{2}, \quad m = 1, 2, 3, \dots$$

Where m correspond to exact mode numbers expressed in terms of frequency

$$\nu_m = \frac{c/n}{\lambda} = \frac{mc}{2Ln}$$

Where c is the speed of light in vacuum and n the index of the active medium

So, an infinite number of longitudinal cavity modes are possible, each with a distinct frequency ν_m

The frequency separation $\Delta\nu$ betⁿ two consecutive modes is given by

$$\Delta\nu = \nu_{m+1} - \nu_m$$

$$= \frac{c}{2Ln} [(m+1) - m]$$

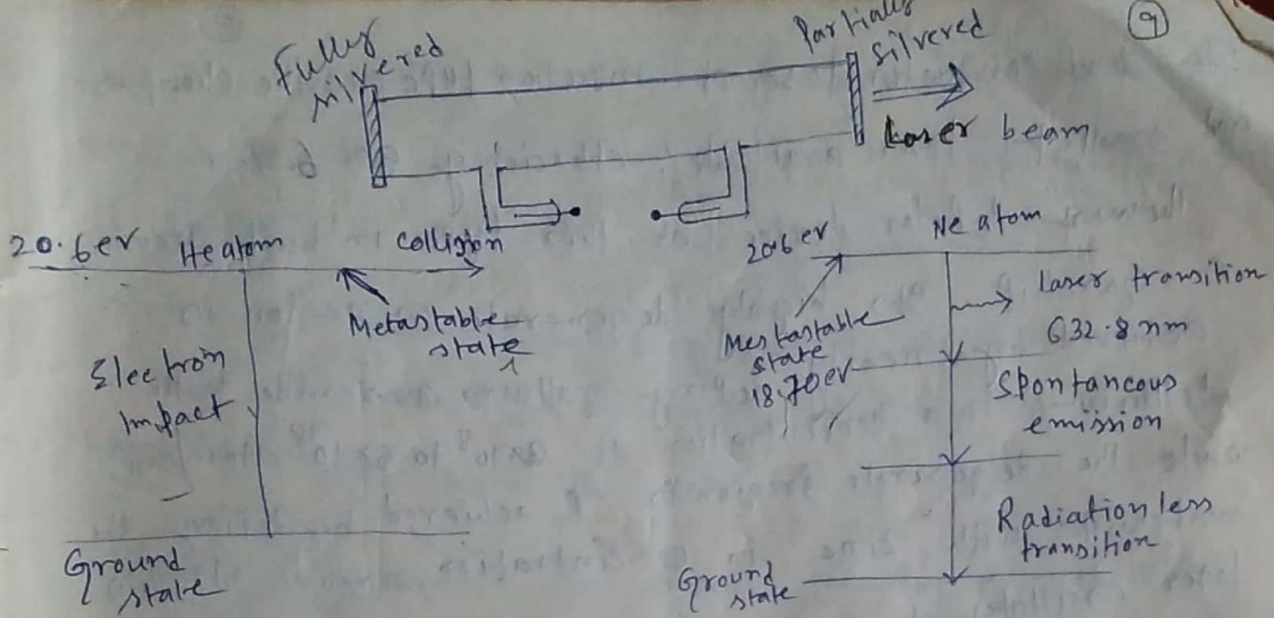
$$\therefore \Delta\nu = \frac{c}{2Ln}$$

The important point to be noted is that the resonant modes of the cavity are narrower in frequency

than the width of a single spontaneous emission line that may engulf several resonant cavity modes. The broad emission line and the narrow cavity modes are illustrated in fig from the comparatively broad range of frequencies of an emission line, the cavity selects and amplifies only certain narrow bands. And it is possible to have, by adjustment of separation of cavity modes, only one mode in the band width of an emission line. This explains the extreme monochromaticity of laser radiation.

⑤
 * Helium-Neon Laser (four lensed laser system)

The helium-neon gas laser achieves a population inversion in a different way. Mixture of about 7 parts of helium and 1 part of neon, at a low pressure (-1mm mercury) is placed in a glass tube that has 11 mirrors. one of them partly transparent at both ends. The spacing of the mirrors is equal to an integral number of half-wave-length of the laser light. An electric discharge is produced in the gas by means of electrodes outside the tube connected to a source of high frequency alternating current and collisions with electrons from the discharge excited He and Ne atoms to metastable state 20.61 and 20.66 eV respectively above their ground state. Some Ne atoms in collision with the He atoms transfer their energy to ground state provided by the kinetic energy of the He atoms. The purpose of the He atoms is thus to help achieve a population inversion in the Ne atoms.

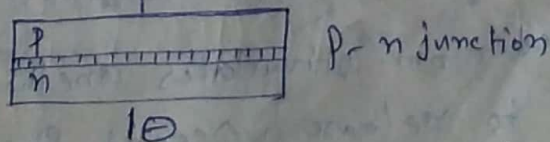


The laser transition in Ne is from the metastable state at 20.66 eV to an excited state at 18.70 eV with the emission of 632.8 nm photon. Then another photon is spontaneously emitted in a transition to a lower metastable state, this transition yields only incoherent light. The remaining excitation energy is lost in collision with the tube walls.

Because the electron impacts that excite the He and Ne atoms occur all the time, unlike the pulsed excitation from the xenon flash lamp in a ruby laser, a He-Ne laser operates continuously.

① Semi Conductor laser

The most common way to the population inversion in semiconductor materials is by joining a p type and an n type materials together. A dc voltage is applied to p-n junction as shown. In forward biasing of the electric field, conduction electrons will be injected from the n side into the junction area, while holes will enter the junction from p side.



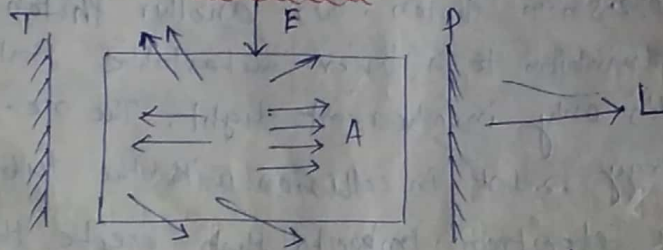
The p-n junction will experience transition of electron from the conduction band into the valence band, that is, they are recombine emitting the surplus energy as radiation. After that placing the system with in optical resonator laser action will take place.

⑨

The semiconductor laser of injection type are the cheapest and smallest laser available, efficiency 50-60%.

The most popular device of this type is built around a GaAs chip. Its highly degenerate n region is achieved by nearly doping gallium arsenide with tellurium in a concentration of 3×10^{18} to 5×10^{18} atom/cm³, while the degenerate p region is achieved by doping the material with zinc in concentration around 10^{19} . This laser oscillates at wave lengths from 0.82 to 0.9 μ m in the infrared.

An Optical resonator:



To sustain laser oscillation, a part of the output must be fed back into the system. Such a positive feedback is brought about by placing the active medium between a pair of plane parallel mirrors facing each other, one at each end of the medium, one of them is a total reflector T and the other a partial one P that allows a part of the generated laser beam L to pass out. The arrangement is known as an optical resonator.

Action: - To cause population inversion, the medium A is fed with pump energy E which is then released from excited atoms by stimulated emission. A photon released by one excited atom stimulates another it encounters in its path to release a second photon, the two coherent photons add completely to a beam of twice the intensity. As the beam courses through the medium, its amplitude rapidly increases. The reflector P reverses the beam allowing it another passage

(10)
In fact, multiple reflections may occur through the excited medium for further amplification, on reaching P, a part L of the beam escapes as a laser beam.

Stimulated photons emitted inclined to the axis are lost through the side of the system so that the final emergent beam is always along the axis.